1-of-2 Non-Inverting Demultiplexer with 3-State Deselected Output

The NL7SZ18 is a high-performance 1-to-2 Demultiplexer operating from a 1.65 V to 5.5 V supply. When the select pin [S] is enabled [high or low], the data in the address pin [A] is routed to one of the output pins $[Y_0 \text{ or } Y_1]$, maintaining a high-impedance on the deselected output pin (See Truth Table).

This device has been optimized for on-board buffering applications and offers mixed (1.65 V, 2.3 V, 3.0 V and 5.5 V) voltage capability by providing over voltage tolerance (OVT*) circuitry on input pins.

Features

- High-Speed Propagation Delay
 tPD 2.5 nS (Typ), Load 50 pF @ 5.0 V
- Power Down Impedance Outputs in High-Z
- Output Drive Capability 4.0 mA to 32 mA
- Broad V_{CC} Operating Range 1.65 V to 5.5 V
- Surface Mount Technology SC-70, 6-Lead Packaging
- OVT* on Inputs Permits 5.0 V to 3.0 V Translation

Typical Applications

- Cell Phones
- PDAs
- Digital Cameras
- Video Cameras
- Hand-Held Sound Devices

Important Information

- ESD Protection: MM >200 V, HBM >2000 V
- Latch-Up Max Rating: 500 mA
- Pin to Pin Compatible with Fairchild's NC7SC18

*Over Voltage Tolerance (OVT) enables input and output pins to function outside (higher) of their operating voltages, with no damage to the devices or to signal integrity.

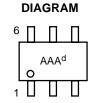


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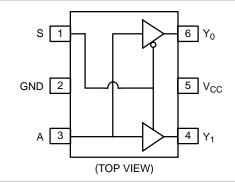


SOT-363/SC70-6/SC-88 DF SUFFIX CASE 419B



MARKING

AAA = Device Marking d = Date Code



PIN/FUNCTION TABLE

Pin	Function
Α	Data Input
S	Demultiplexer Select
Y ₀	Output 1
Y ₁	Output 2

TRUTH TABLE

Inp	out	Out	put
S	Α	Y ₀	Y ₁
L	L	L	Z
L	Н	Н	Z
Н	L	Z	L
Н	Н	Z	Н

ORDERING INFORMATION

Device	Package	Shipping
TBD	SOT-363/ SC70-6/ SC-88	TBD

NL7SZ18

MAXIMUM RATINGS

Symbol	Rating		Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to +7.0	V	
V _{IN}	DC Input Voltage		-0.5 to +7.0	V
V _{OUT}	DC Output Voltage		-0.5 to +7.0	V
I _{IK}	DC Input Diode Current	@ V ₁ < -0.5 V	-50	mA
I _{OK}	DC Output Diode Current	@ V ₁ < -0.5 V	-50	mA
I _{OUT}	DC Output Sink Current		±50	mA
I _{CC}	DC Supply Current per Supply Pin		±100	mA
I _{GND}	DC Ground Current per Ground Pin	±100	mA	
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Secon	nds	260	°C
TJ	Junction Temperature Under Bias		+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 1)		250	°C/W
P_{D}	Power Dissipation in Still Air at 85°C		180	mW
MSL	Moisture Sensitivity		Level 1	-
F _R	Flammability Rating	ammability Rating Oxygen Index: 28 to 34		
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 200 n/a	V

Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum-rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

- 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.
- Tested to EIA/JESD22-A114-A.
 Tested to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.

RECOMMENDED OPERATING CONDITIONS

Symbol		Value	Unit	
V _{CC}	DC Supply Voltage		1.65 to 5.5	V
V _{CC}	DC Supply Voltage, Data Retention		1.5 to 5.5	V
V _{IN}	Input Voltage		0 to 5.5	V
V _{OUT}	Output Voltage		0 to 5.5	V
T _A	Operating Temperature		-40 to 85	°C
t _r , t _f	Input Rise and Fall Times	$\begin{array}{c} V_{CC} @ 1.8 \pm 0.15 V \\ V_{CC} @ 2.5 \pm 0.2 V \\ V_{CC} @ 3.3 \pm 0.3 V \\ V_{CC} @ 5.0 \pm 0.5 V \end{array}$	0 to 20 0 to 20 0 to 10 0 to 5	nS/V
θ_{JA}	Thermal Resistance		350	°C/W

NL7SZ18

DC ELECTRICAL CHARACTERISTICS

				V _{CC}	T _A = 25°C			$T_A = -40^{\circ}C \text{ to } 85^{\circ}C$		
Symbol	Parameter	Co	ndition	(V)	Min	Тур	Max	Min	Max	Unit
V _{IH}	High-Level Input Voltage			1.65-1.95 2.3-5.5	0.75 V _{CC} 0.70 V _{CC}			0.75 V _{CC} 0.70 V _{CC}		V
V_{IL}	Low-Level Output Voltage			1.65-1.95 2.3-5.5			0.25 V _{CC} 0.30 V _{CC}		0.25 V _{CC} 0.30 V _{CC}	V
			I _{OH} = -100 μa	1.65 2.3 3.0 4.5	1.55 2.20 2.90 4.40	1.65 2.30 3.00 4.50		1.55 2.20 2.90 4.40		
V _{OH}	High-Level Output Voltage	$V_{IN} = V_{IH}$	I_{OH} = -4.0 mA I_{OH} = -8.0 mA I_{OH} = -16 mA I_{OH} = -24 mA I_{OH} = -32 mA	1.65 2.3 3.0 3.0 4.5	1.29 1.90 2.40 2.30 3.80	1.52 2.15 2.80 2.68 4.20		1.29 1.90 2.40 2.30 3.80		V
	Low-Level		I _{OL} = 100 μa	1.65 2.3 3.0 4.5		0.0 0.0 0.0 0.0	0.10 0.10 0.10 0.10		0.10 0.10 0.10 0.10	
V _{OL}	Output Voltage	$V_{IN} = V_{IL}$	$I_{OL} = 4.0 \text{ mA}$ $I_{OL} = 8.0 \text{ mA}$ $I_{OL} = 16 \text{ mA}$ $I_{OL} = 24 \text{ mA}$ $I_{OL} = 32 \text{ mA}$	1.65 2.3 3.0 3.0 4.5		0.08 0.10 0.15 0.22 0.22	0.24 0.30 0.40 0.55 0.55		0.24 0.30 0.40 0.55 0.55	V
I _{IN}	Input Leakage Current	V _{IN} = 5	5.5 V, GND	0.0 to 5.5			±0.1		±1.0	μΑ
l _{OZ}	Output High-Z Current		V_{IH} or V_{IL} out $\leq 5.5 \text{ V}$	1.65 to 5.5			±0.5		±5.0	μΑ
l _{OFF}	Power-Off Leakage Current	V _{IN} or \	V _{CC} = 5.5 V	0.0			1.0		10	μΑ
I _{CC}	Quiescent Supply Current	V _{IN} = 5	5.5 V, GND	1.8 to 5.5			1.0		10	μΑ

AC ELECTRICAL CHARACTERISTICS

				T _A = 25°C		T _A = 25°C		T _A = -40°C to = 25°C 85°C				
Symbol	Parameter	Condition	V _{CC}	Min	Тур	Max	Min	Max	Unit	Figure		
t _{PLH}	Propagation Delay	C_L = 15 pF R_D = 1.0 M Ω S = OPEN	$\begin{array}{c} 1.8 \pm 0.15 \\ 2.5 \pm 0.2 \\ 3.3 \pm 0.3 \\ 5.0 \pm 0.5 \end{array}$	2.0 1.0 0.8 0.5	6.3 3.6 2.7 2.0	10.1 5.7 4.0 3.1	2.0 1.0 0.8 0.5	10.5 6.0 4.3 3.3	nS	Figures 1 & 3		
t _{PHL}	A to Y ₀ or Y ₁	$C_L = 50 \text{ pF}$ $R_D = 500 \Omega$ $S = OPEN$	3.3 ± 0.3 5.0 ± 0.5	1.2 0.8	3.4 2.5	4.9 3.9	1.2 0.8	5.4 4.2	nS	Figures 1 & 3		
^t PZL t _{PZH}	Output Fachla Time	$C_L = 50 \text{ pF}$ $R_D, R_U = 500 \Omega$ $S = \text{GND for } t_{PZH}$ $S = V_{IN} \text{ for } t_{PZL}$ $V_I = 2 \text{ x } V_{CC}$	1.8 ± 0.15 2.5 ± 0.2 3.3 ± 0.3 5.0 ± 0.5	3.0 1.8 1.2 0.8	6.9 4.2 3.2 2.5	12 6.8 5.0 4.0	3.0 1.8 1.2 0.8	12.5 7.3 5.5 4.3	nS	Figures 1 & 3		
t _{PLZ}	Output Enable Time	$C_L = 50 \text{ pF}$ $R_D, R_D = 500 \Omega$ $S = \text{GND for } t_{PHZ}$ $S = V_{IN} \text{ for } t_{PLZ}$ $V_I = 2 \text{ x } V_{CC}$	1.8 ± 0.15 2.5 ± 0.2 3.3 ± 0.3 5.0 ± 0.5	2.5 1.5 0.8 0.3	6.0 4.0 2.9 1.8	10 6.8 4.9 3.5	2.5 1.5 0.8 0.3	10.5 7.1 5.3 3.7	nS	Figures 1 & 3		
C _{IN} C _{OUT}	Input Capacitance Output Capacitance		OPEN 3.3		2.5 4.0				pF			
C _{PD}	Power Dissipation Capacitance	Note 5	3.3 5.0		16 19.5				pF	Figure 2		

^{5.} C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle (see Figure 2). C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CCD}static).

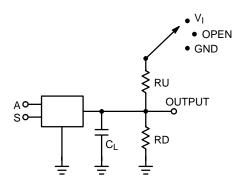


Figure 1. AC Test Circuit

 C_L Includes Load and Stray Capacitance Input PRR = 1.0 MHz; t_W = 500 nS

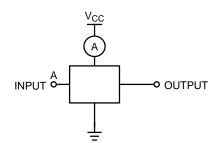
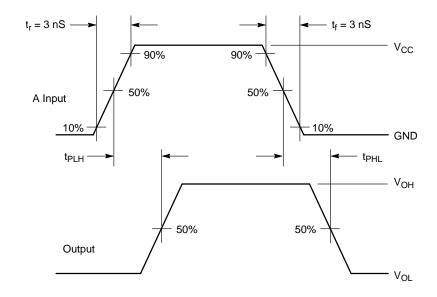


Figure 2. I_{CCD} Test Circuit

 $\begin{aligned} & \text{Input} = \text{AC Waveform; } t_r = t_f = 1.8 \text{ nS} \\ & \text{PRR} = 10 \text{ MHz; } \text{Duty Cycle} = 50\% \\ & \text{S Input} = \text{GND or x} \end{aligned}$



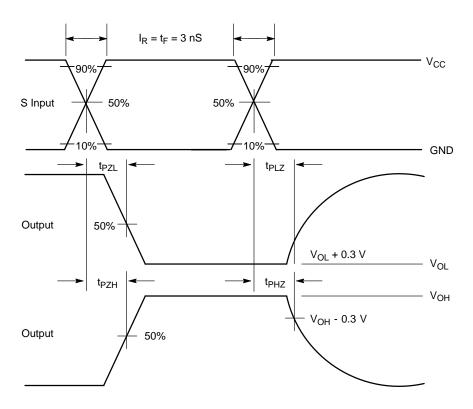


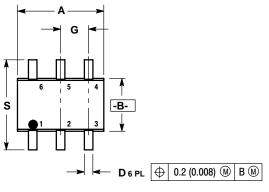
Figure 3. AC Waveforms

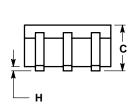
NL7SZ18

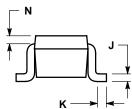
PACKAGE DIMENSIONS

SOT-363/SC70-6/SC-88 **DF SUFFIX**

6-LEAD PACKAGE CASE 419B-02 ISSUE N







NOTES:

- DIMENSIONING AND TOLERANCING
- PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- 3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

	INC	HES	MILLIM	ETERS			
DIM	MIN	MAX	MIN	MAX			
Α	0.071	0.087	1.80	2.20			
В	0.045	0.053	1.15	1.35			
С	0.031	0.043	0.80	1.10			
D	0.004	0.012	0.10	0.30			
G	0.026	0.026 BSC		BSC			
Н		0.004		0.10			
J	0.004	0.010	0.10	0.25			
K	0.004	0.012	0.10	0.30			
N	0.008	REF	0.20	REF			
S	0.079	0.087	2.00	2.20			

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